

### Laser-based high-pressure, high-strain-rate materials experiments

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### Outline



- Introduction
  - Solid-state experiments at high pressure on a laser
- High pressure strength
  - RT instability in solid AI at high pressure to infer Y(P)
- Dynamic material response
  - Dynamic x-ray diffraction of the lattice level response in Si and Cu
- Wave profile and residual deformation
  - VISAR measurement, sample recovery and characterization

The high pressure response of materials is of interest for many reasons; lasers provide a way to access high pressures and strain rates



- The core of the earth is Fe at 3 Mbar, both solid and liquid
  - Long time scale, diamond anvil experiments
- Survivability of passengers in a car crash depend on the material response of the car
  - ms- $\mu$ s time scale, Hopkinson bar and gun experiments
- Space station wall integrity from space debris, dust, micro-asteroids
  - $-\mu$ s time scale, gun and high explosives experiments



Lasers access unique high pressure, high strain rate regime of material response to test the limits of theories and scaling laws

# **Example - strength measurements at high pressure using a high explosive drive and modulated AI plate**

- Shockless HE drive used to compress and accelerate a plate with preimposed modulations
- Pre-imposed modulations grow by the Rayleigh-Taylor instability
- The growth is reduced from classical (fluid) due to material strength



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**1. Solid state RT instability experiment** 

- An internally shielded hohlraum is used to shock compress an Al-6061 metal foil at high pressure
- Internal shields block hard x-rays from preheating package
- A shaped laser pulse generates a series of gentle shocks for nearly isentropic compression



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## Detailed simulations predict that the AI foil remains solid throughout the experiment

- The AI remains below the melt curve
- The foil trajectory is nearly isentropic to 1.8 Mbar

 $T_{m} = T_{m_{o}} e^{2a(1-\eta)} \eta^{2(\gamma_{o} - a - 1/3)}$ Lindemann melt model Pressure and temperature at the Calculated internal energy embedded interface trajectory 10 0.6 2.0 Internal energy (kJ/g) D 0.5 Hugoniot 8 Temperature (eV) Pressure (Mbar) 1.5 0.4 6 Melt curve 0.3 1.0 melt Isentrope<sup>-</sup> 4 0.2 0.5 2 0.1 Internal energy interface 0.0 0.0 0 1.0 12 1.6 1.8 2.0 10 15 20 14 5 0 Time (ns) Normalized density



## Simulations of the instability growth demonstrate sensitivity to the strength of the Al



• Growth rates with strength are expected to be reduced from classical (fluid)

Steinberg-Guinan constitutive model

$$Y = Y_o \left( 1 + \beta \left( \varepsilon + \varepsilon_i \right) \right)^n \frac{G(P, T)}{G_o}$$
$$G = G_o \left( 1 + \left( \frac{G_P}{G_o} \right) \frac{P}{\eta^{1/3}} - \left( \frac{G_T}{G_o} \right) (T - 300) \right)$$

Predicted growth factors  $\lambda$ =20  $\mu$ m



$$\eta_{c} = \eta_{D} \left[ \mathbf{1} - \mathbf{0.86} e^{-\frac{2\pi H}{\sqrt{3}\lambda}} \right] \left\{ \left[ \mathbf{1} - e^{-\frac{2\pi H}{\sqrt{3}\lambda}} \right]^{2} - \left[ \frac{\lambda}{\lambda_{M}} \right]^{2} \right\}$$
$$\eta_{D} = \frac{2Y}{\rho g} \qquad \lambda_{M} = \frac{4\pi G}{\rho g}$$

Stability curve (Nizovtsev and Rayevsky, 1991)



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## The RT growth is nearly fluid at early times, but it is suppressed at later times



- Modeling was done assuming the following:
  - Fluid
  - Nominal Steinberg-Guinan
  - Fluid until 13 ns, then S-G with theoretical maximum Y=G/10



The RT growth is nearly fluid at early times, but it is suppressed at later times; suggestive of model from Grady/Asay and data by Rayevsky and Lebedev

- High pressure strain causes localized heating and softening in shear bands; bulk AI flows as fluid due to localized deformation
- As heat conducts into the bulk material, the metal regains bulk solid strength and continued growth is inhibited

**Optical emission from shocked quartz** 

Shocked HE experiments show fluid-like response with saturation

Brannon *et al*, SCCM 1983.

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# The late time images show features that may be due to hydrodynamic imprinting of the grain structure

- The spatial scale of the late-time modulation is similar to initial grain structure
- 2D simulations incorporating the grain boundaries start to show effects at t=18 ns, 3D simulation has been started



Simulations by G. Bazan, 2001

### 2. Dynamic x-ray diffraction



- In situ x-ray diffraction probes the long range lattice order under shock compression
- Shock pressure generated using a hohlraum x-ray drive or by direct laser irradiation
- Time-resolution with x-ray streak cameras provides information on dynamic lattice response



### Simultaneous measurements of orthogonal planes indicates Si responds uniaxially on a ns time scale



- 40  $\mu$ m thick Si shocked along (100) axis
- P=115-135 kbar; HEL=84 kbar



## Cu undergoes a transition to 3D lattice compression at high pressure



- 8  $\mu$ m single crystal Cu shocked along (100) axis
- P = 180 kbar; HEL ~ 2 kbar



## The timescale for plastic deformation in Si is much longer than for Cu based on Orowan's equation



**Orowan equation:** 
$$\frac{\Delta \epsilon}{\Delta t} = N |\mathbf{b}| \mathbf{v}$$

### Silicon

- $\Delta t > 1 \mu s$  : dislocations do not move
  - -5% strain, dislocations separated by at least the Burger's vector (3.8 Å) (diffraction linewidth indicates N <  $10^{14}$  m<sup>-2</sup>)
  - Linear extrapolation of dislocation velocity in Si (0.1 mm/s)

### Copper

### • $\Delta t < 10 \text{ ps}$ : dislocations do move

- -5% strain, dislocations separated by at least the Berger's vector (2.5 Å)
- Velocity of dislocations calculated to be 400 m/s in MD simulations



Introduction to Dislocations, Hull and Bacon (Fig. 3.12)

### The time scale for plastic deformation in Si is much longer than for Cu, due to its high Peierls barrier and activation energy



• For  $\sigma < Y_{p}$ : thermal activation regime, and

$$t = t_{wait} = \frac{1}{v_{attempt} \exp\left[\frac{-\Delta F}{kT} \left(1 - \frac{\sigma}{Y_P}\right)^2\right]}$$

• For  $\sigma > Y_{P}$ : phonon drag regime,  $t = t_{run} = \frac{aB}{\sigma b}$ 



Assume that  $\sigma$  = 3 GPa, and kT = 0.05 eV:

For Si:

$$\begin{split} Y_{\rm P} &= 0.07 {\rm G}_0(1 + {\rm AP}/\eta^{1/3}) > 0.07 {\rm G}_0 \\ {\rm giving} \ Y_{\rm P} &> 0.07 \ (63.7 \ {\rm GPa}) = 4.5 \ {\rm GPa}, \\ \Delta F &= 0.2 {\rm Gb}^3 = 0.2 \ (63.7 {\rm GPa}) \ (3.83 \ {\rm A})^3 = 4.5 \ {\rm eV} \end{split}$$

So  $\sigma < Y_P$ , and kT <<  $\Delta F$ : thermal activ. regime

Assume  $v_{\text{attempt}} = v_{\text{Debye}} / 100 = 10^{11} \text{ s}^{-1}$ , So  $1/t_{\text{wait}} = (10^{11} \text{ s}^{-1}) \exp[-(4.5/.05) (1-3/4.5)^2]$ 

Giving t<sub>wait</sub> > ~150 ns, meaning <u>slow</u>

#### For Cu:

 $Y_P = (6.3 \times 10^{-3})G_0(1+AP/\eta^{1/3}) = 0.42$  GPa So  $\sigma > Y_P$ , meaning phonon drag regime

Assume  $B = 10^{-10} MPa \cdot s$ , and  $a/b < 10^3$ ,

So t<sub>run</sub> < (10<sup>3</sup>) (10<sup>-10</sup> MPa·s)/(3 GPa) = 30 ps: <u>fast</u>

### A new wide-angle film detector is used to record many more lattice planes



- X-rays diffracted from orthogonal lattice planes are recorded with 2 xray streak cameras
- A segmented film assembly records x-rays diffracted over a  $\pi$ -solid angle from many more lattice planes



### Detailed response of the lattice is better understood by recording diffraction from other lattice planes

- Large angle detector has been fielded on Si shock experiments
- Shift of many different lines is observed; details are being studied



### 3. VISAR wave profiles and sample recovery



- AI-6061 wave profile measurements show elastic-plastic response with spall on release
- Fitting the shock breakout wave profile provides best-fit strength parameters



# VISAR wave profiles provide information on the strength parameters for the shocked metal

- The wave profile is sensitive to the constitutive model parameters for the metal foil
- Best-fit wave profile provides model parameters:
  - Shear modulus G=320 kbar (276)
  - Bulk modulus K=794 kbar (742)
  - Yield strength Y=4.27 kbar (2.9)



### Transmission electron and optical microscope analysis shows residual structure that depends on the drive conditions



- Shocked samples are recovered in a low density foam-filled tube
- Preliminary tests done at OMEGA; shock pressure is ~400 kbar, decays to ~25 kbar at the rear surface



## TEM analysis of recovered Cu shows the residual microstructure



- Residual microstructure of recovered single crystal Cu samples
- Higher pressures show twinning



### **Summary**



- Solid state hydrodynamic instability
  - RT instability in AI to infer Y(P)
  - There is possible imprinting due to the initial grain structure
- In situ dynamic x-ray diffraction
  - Time-resolved diffraction relates the lattice behavior to the macroscopic response of Si and Cu under shock loading
  - Si responds uniaxially, Cu deforms plastically
- Shock/recovery experiments
  - Residual deformation structure in Cu depends on the shock pressure